A Josephson quantum phase battery


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A battery is a classical apparatus which converts a chemical reaction into a persistent voltage bias able to power electronic circuits. Similarly, a phase battery is a quantum equipment which provides a persistent phase bias to the wave function of a quantum circuit. It represents a key element for quantum technologies based on quantum coherence. Unlike the voltage batteries, a phase battery has not been implemented so far, mainly because of the natural rigidity of the quantum phase that, in typical quantum circuits, is imposed by the parity and time-reversal symmetry constrains. Here we report on the first experimental realization of a phase battery in a hybrid superconducting circuit. It consists of an n-doped InAs nanowire with unpaired-spin surface states and proximitized by Al superconducting leads. We find that the ferromagnetic polarization of the unpaired-spin states is efficiently converted into a persistent phase bias \( \varphi_0 \) across the wire, leading to the anomalous Josephson effect [1, 2]. By applying an external in-plane magnetic field a continuous tuning of \( \varphi_0 \) is achieved. This allows the charging and discharging of the quantum phase battery and reveals the symmetries of the anomalous Josephson effect predicted by our theoretical model. Our results demonstrate how the combined action of spin-orbit coupling and charge interaction breaks the phase rigidity of the system inducing a strong coupling between charge, spin and superconducting phase. This interplay opens avenues for topological quantum technologies [3], superconducting circuitry [4, 5] and advanced schemes of circuit quantum electrodynamics [6, 7].

The robustness of the macroscopic superconducting phase makes superconducting circuits an ideal platform to develop artificial atoms on-chip for fundamental experiments of atomic physics and quantum optics [8], and represents nowadays one of the most promising and scalable technologies to develop quantum computers [9, 10] as well as ultra-fast classical electronics [11]. At the base of phase-coherent superconducting circuits is the Josephson effect [12]: a quantum phenomenon describing the flow of a dissipationless current in weak-links between two superconductors. The Josephson current \( I_J \) is then intimately connected to the macroscopic phase difference \( \varphi \) between the two superconductors via the so-called current-phase relationship (CPR) \( I_J(\varphi) \). If either time-reversal \( (t \rightarrow -t) \) or inversion \( (\vec{r} \rightarrow -\vec{r}) \) symmetries are preserved, \( I_J(\varphi) \) is an odd function of \( \varphi \) and the CPR, in its simplest form, reads \( I_J(\varphi) = I_C \sin(\varphi) \) [13], with \( I_C \) being the junction critical current. This means that, as long as one of these symmetries is preserved, an open Josephson junction \( (JJ) \) \( (I_J = 0) \) cannot provide a phase bias or, accordingly, a JJ closed on a superconducting circuit \( (\varphi = 0) \) cannot generate current. As a consequence, the implementation of a phase battery is prevented by these symmetry constraints which impose a rigidity on the superconducting phase.

The break of time-reversal symmetry alone, maintains the phase-rigidity but enables two possible phase shifts 0 or \( \pi \) in the CPR. The 0-\( \pi \) transition has been extensively studied in superconductor/ferromagnet/ superconductor junctions [13–15] which have applications in cryogenic memories [16, 17]. It is worth noticing that these symmetry arguments are universal and apply not only for the superconducting phase but for any quantum phase, for example, 0-\( \pi \) phase-rigidity have been observed in normal metals [18], semiconductors [19–22], graphene [23], topological insulators [24] as well as hybrid systems [25].

On the other hand, if both, time reversal and inversion symmetries are broken a finite phase shift \( 0 < \varphi_0 < \pi \) can be induced [2, 26]. As already anticipated in the pioneering work of Josephson [12], in this case the CPR reads:

\[
I_J(\varphi) = I_C \sin(\varphi + \varphi_0). \quad (1)
\]

A junction with such CPR, defined as a \( \varphi_0 \)-junction, will generate a constant phase bias \( \varphi = -\varphi_0 \) in an open cir-
circuit configuration, while inserted into a closed superconducting loop will induce a current $I = I_C \sin(\phi_0)$, usually denoted as anomalous Josephson current. Recently, anomalous Josephson currents have been the subject of theoretical \cite{27-30} and experimental works \cite{31, 32} envisioning direct applications on superconducting electronics and spintronics \cite{4, 33}.

Lateral hybrid junctions made of materials with a strong spin-orbit interaction (SOI) \cite{31} or topological insulators \cite{32} represent ideal candidates to engineer Josephson $\phi_0$-junctions. The lateral arrangement breaks the inversion symmetry and provides a natural polar axis $\hat{z}$ perpendicular to the current direction. Moreover, the electron spin polarization $\pmb{s}$ induced by either a Zeeman field or the exchange interaction with ordered magnetic impurities, breaks the time-reversal symmetry. As a result, the structure acquires a toroid symmetry described by the anapole moment $\pmb{t} \sim (\hat{z} \times \pmb{s})$ thereby allowing magnetoelectric effects in the presence of SOI to occur \cite{2, 34}. In this case, the anomalous $\phi_0$-shifts is ruled by the Lifshitz-type invariant in the free energy ($F_L$), which can be compiled from the product of the anapole moment and the superfluid velocity \cite{2},

$$ F_L \sim f(\alpha, h) (\pmb{n}_h \times \hat{z}) \cdot \pmb{v}_s, $$

where $f(\alpha, h)$ is an odd function of the strength of the Rashba SOI $\alpha$ and the exchange or Zeeman field $h$, $\pmb{n}_h$ is a unit vector pointing in the direction of the latter, and $\pmb{v}_s$ is the superfluid velocity of the Cooper pairs flowing in the JJ. The scalar triple product then defines the vectorial symmetries of $\phi_0$, while the amplitude of the shift depends on sample specific microscopic details as well as macroscopic quantities like temperature.

Driven by the geometric condition for a finite $\phi_0$-shift,
Eq. (2), we present the first experimental realization of a phase battery (Fig. 1a and b), consisting of a JJ made of an InAs nanowire (in red) embedded between two Al superconducting poles (in blue). Here the supercurrent, and hence $\mathbf{v}_s$, flows along the wire ($x$-direction) and orthogonal to the Rashba SOI vector of the InAs nanowire pointing out of the substrate plane ($z$-direction) hosting the device. In the same nanowire, surface oxides or defects generate unpaired spins behaving like magnetic impurities (represented by yellow arrows in Fig. 1a) that can be polarized along the $y$-direction to provide an exchange interaction $h$ in this direction. This leads to a finite triple product in Eq. (2) and, consequently, to the anomalous $\varphi_0$ phase bias. Due to the ferromagnetic order of the unpaired spins, the phase bias persists even in the absence of an applied magnetic field. This demonstrates the realization of a controllable phase battery which converts the ferromagnetic order into a quantum phase bias. We show that the $\varphi_0$-shift is odd in the polarization of the magnetic impurities, as expected from Eq. (2), and can be also controlled by the Zeeman interaction with an external magnetic field ($B$). By scanning the $\varphi_0$-shifts over all the directions of the in-plane $B$-field we reveal the geometrical origin of the anomalous phase described by Eq. (2).

An Al-based superconducting quantum interference device (SQUID) is used as a phase-sensitive interferometer made with two $\varphi_0$ JJs (in red), as shown in the sketch of Fig. 1b and in the false-color scanning electron micrograph of Fig. 1c. The SQUID geometry maximizing the symmetry of the two JJs [35] has been conceived to measure the anomalous phase-shift, and yields the accumulation of two anomalous $\varphi_0$-shifts across the two JJs when applying an uniform in-plane magnetic field (see SI for further details). The anomalous phase shift in the SQUID critical current, is then given by:

$$I_S(\Phi) = 2I_C \cos \left( \frac{\Phi}{\Phi_0} + \frac{\varphi_{\text{tot}}}{2} \right),$$

where $I_C$ is the critical current of each JJ, $\Phi$ is the magnetic flux piercing the ring, $\varphi_{\text{tot}} = 2\varphi_0$ is the total anomalous phase shift in the SQUID interference pattern resulting from the $\varphi_0$-shifts in each JJs (see SI for details), and $\Phi_0 = 2.067 \times 10^{-15}$Wb is the flux quantum. This model provides a good description of the SQUID interference pattern displayed in Fig. 1e, which shows the voltage drop across the SQUID as a function of the out-of-plane magnetic field $B_z$ and bias current $I$. The red-colored region of Fig. 1e, corresponding to zero-voltage drop, indicates the dissipationless superconducting regime and the edge of this region provides the $I_S(\Phi)$ dependence. The periodicity of $I_S$ as a function of $B_z$ translates into a periodicity on the flux $\Phi = B_z A$ through the ring with an effective area $A \approx 4.9\mu m^2$, consistent with the area estimated from the SEM image of Fig. 1c. The green line on top of the color plot is the best-fit of $I_S(\Phi)$ from Eq. (3), with $I_C \approx 300$ nA and no phase-shift $\varphi_{\text{tot}} \approx 0$. The latter condition is consistent with the absence of the anomalous phase when the magnetic field has only a component in $\hat{z}$ direction and the magnetic impurities are not polarized (i.e. $\mathbf{n}_B \parallel \hat{z}$ in Eq. (2)). Notably, there is a replica of the $I_S(\Phi)$ oscillations in the voltage drop $\Delta V(\Phi)$ when $I > I_S$, and the SQUID operates in the dissipative regime (blue region and curve in Figs. 1e-f), as conventionally realized with strongly overdamped JJs [36]. This oscillation provides a complementary and fast method to quantify the SQUID phase shifts and is used in the following analysis. Additional measurements on similar devices can be found in the SI.

In addition, in our characterization of the interferometer we have measured the temperature dependence of its normal state resistance (see Fig. 1d). This shows a clear upturn below $\sim 80$K, which is a clear signature of the presence of magnetic impurities increasing, at low temperature, the electron scattering events. The measured temperature dependence can be well fitted within the Kondo theory (yellow line of Fig. 1d) [37]. From the fit we deduced a density of magnetic impurities of $\sim 4$ ppm (see SI for more details on the fitting procedure). The presence of these unpaired spins can be ascribed to the nanowire surface oxides, as already observed in undoped metal oxide nanostructures [38, 39], even if defects in the nanowire crystalline structure [40] cannot be excluded a priori. Although, the amount of intrinsic magnetic impurities is not fully controllable, their presence is crucial for the operation and implementation of the phase battery, as discussed below.

Following the condition imposed by a finite Lifshitz invariant term (Eq. (2)) we apply an in-plane magnetic field orthogonal to the nanowire axis ($B_y$). The $I_S(\Phi)$ dependence then evolves with a clear generation of an anomalous phase shift, as presented in the panels of Fig. 2. The evolution of $\Delta V(\Phi)$ as a function of $B_y$ ranging from $-60$ mT up to $60$ mT is visible in Fig. 2a and in the selected single traces of Fig. 2b. The resulting phase-shift, $\varphi_{\text{tot}}$, exhibits a non-monotonic evolution as a function of $B_y$, with a maximum shift at $B_y \approx 5$ mT and a saturation for $|B_y| \gtrsim 30$ mT (yellow curve in Fig. 2c). When the field is reversed, a hysteretic behavior is observed (green curve in Fig. 2c), and the evolution of $\varphi_{\text{tot}}$ reverses with a minimum shift at $B_y \approx -5$ mT. The change of sign of the phase-shift agrees with the theoretical prediction of Eq. (2) when $h \rightarrow -h$, whereas the observed hysteretic behavior suggests a ferromagnetic coupling between the magnetic impurities in the nanowire. At low temperatures, the coexistence of Kondo and ferromagnetism is not unusual [39] and well describes the hysteretic non-monotonic behavior observed in $\varphi_{\text{tot}}(B_y)$. Indeed, due to the antiferromagnetic nature of the Kondo interaction, the effective exchange field created by these unpaired spins is opposite to the Zeeman field generated by $B_y$ so that the two contributions are competing in the anomalous phase with a partial cancellation.

This additional component is confirmed by the observation of an intrinsic phase-shift, $\varphi_{\text{int}}$, which is finite even in the absence of the in-plane magnetic field.
FIG. 2. Charging loops of the Josephson phase battery. a, Voltage drop $\Delta V(\Phi)$ at constant current bias $I = 1 \mu A$ vs in-plane magnetic field $B_y$ applied orthogonal to the nanowire axis. At large $|B_y|$, the amplitude of $\Delta V(\Phi)$ is lowered due to the suppression of superconductivity inside the wire. Each trace is vertically offset for clarity. b, Selected traces $\Delta V(\Phi)$ extracted from a for different $B_y$. Data are vertically offset for clarity. c, Extracted phase shift $\varphi_{\text{tot}}$ from the curves in a with back (green) and forth (yellow) sweeps in $B_y$. The shifts are extracted by comparing the single traces to the RSJ relation $\Delta V = \frac{B}{2} \sqrt{I^2 - 4I_c^2 \cos \left(\frac{\pi\Phi}{\Phi_0} + \varphi_{\text{tot}}\right)}$ [36], see the dashed line in b which serves as an example. d, Color plot of the persistent voltage drop $\Delta V(\Phi)$ measured at $B_y = 0$ after the magnetic field was swept to the values shown on the $y$-axis. e, Selected traces $\Delta V(\Phi)$ extracted from d. f, Intrinsic phase shift $\varphi_{\text{int}}$ extracted from d. $\varphi_{\text{int}}$ stems from the ferromagnetic polarization of the unpaired spins. All data were recorded at 80 mK of bath temperature.

$(B_y = 0)$ if previously a $B_y$ has been applied, as shown in Figs. 2d and e. Since it stems from a ferromagnetic ordering, $\varphi_{\text{int}}$ depends only on the history of $B_y$, and again, the evolution of $\varphi_{\text{int}}(B_y)$ can be extracted and is presented in Fig. 2f. In contrast to the total phase-shift, $\varphi_{\text{int}}$ follows a clear and almost monotonic behavior which shows a hysteresis in the back and forth sweep direction (blue and red curves of Fig. 2f). $\varphi_{\text{int}}$ saturates at $|B_y| \gtrsim 15 \text{ mT}$ in the two asymptotic limits with total phase drop of $\sim \pi$. Furthermore, during the first magnetization of the SQUID, a clear curve resembling the initial magnetization curve of a ferromagnet has been observed (see SI Fig. 2S), confirming the ferromagnetic nature of the impurity ensemble. The extracted $\varphi_{\text{int}}$ then implements the intriguing concept of a quantum phase battery, i.e., a passive electronic element able to provide an independent and sizable phase bias that can be "charged" at will by polarizing the magnetic impurities with a small external magnetic field of $\sim \text{ mT}$.

We now analyze the extrinsic contribution, $\varphi_{\text{ex}}$, to the phase shift which stems directly from the external $B$-field. Due to the additive nature of the anomalous phase in the exchange field, $h$ in Eq. (2), it is possible to extract from $\varphi_{\text{tot}}$ the extrinsic contribution $\varphi_{\text{ex}} = \varphi_{\text{tot}} - \varphi_{\text{int}}$. This is depicted in Fig. 3a, where the evolution of $\varphi_{\text{ex}}$ in $B_y$ is shown. Here, the agreement between the back (blue) and forth (red) traces in $B_y$ demonstrates explicitly the absence of any hysteresis ensuring the complete extraction of the intrinsic contribution. Notice also that the behavior of $\varphi_{\text{int}}$ and $\varphi_{\text{ex}}$ in the magnetic field is opposite in sign as expected from the competition between the exchange interactions induced by the Kondo antiferromagnetic coupling and a Zeeman field, then further supporting our assumptions. The dependence $\varphi_{\text{ex}}(B_y)$ is characterized by a linear increase at low magnetic fields ($|B_y| < 15 \text{ mT}$) up to a maximum phase-shift of $\pm \pi/2$. Remarkably, our measurement reveals, for the first time, the odd parity of the anomalous phase with respect to the
magnetic field, one of the main symmetry hallmarks of this effect [1, 2]. This parity is the consequence of the odd parity of the free energy $F_L$ with respect to the exchange field. At higher fields non-linearities appear suggesting a non-trivial evolution of $\varphi_{ex}$ in the magnetic field. In order to understand this behavior we have modelled our $\varphi_0$-junction setup by a lateral junction treated within the quasiclassical approach presented in Ref. [2] (see SI). The resulting $\varphi_0$ obtained from the above model, is shown in the inset of Fig. 3a. It nicely reproduces the main features of $\varphi_{ex}$: the linear dependence at small magnetic fields and the saturation at larger ones. In particular, at small in-plane fields ($B_{in} = \sqrt{B_x^2 + B_y^2}$) the model leads to a simple expression for the anomalous phase:

$$\varphi_{ex} \simeq C_1 \alpha^3 B_{in} \sin \left(\theta\right) + O(B_{in}^3),$$

where $\theta$ is the angle between the field and the nanowire axis and $C_1$ is a parameter dependent on the temperature and the microscopic details of the JJ (see Fig 3b). By using typical values of the parameters for the InAs/Al junction we obtained a $C_1 \approx 0.04\pi$ mT, in very good agreement with the experimental data (see SI).

The odd symmetry of the anomalous phase dictated by the triple product in Eq. (2) can be further investigated by measuring $\varphi_{ex}$ over all the directions of the in-plane magnetic field. Figure 3b shows the full dependence of $\varphi_{ex}$ on the angle $\theta$ (see sketch in Fig. 3b). As predicted from Eq. (2), the phase-shift is very small for fields along the nanowire axis ($\theta = 0$, green trace in Fig. 3b), showing the maximum slope for the orthogonal magnetic field ($\theta = \pi/2$, blue trace in Fig. 3b). The odd symmetry manifests clearly as well in the slope $d\varphi_{ex}/dB_{in}$ in the low-field limit (Fig. 3c). The latter is perfectly fitted with a sinusoidal function of $\theta$ in agreement with Eq. (4) (red trace in Fig. 3c).

In summary, our results demonstrate the very first implementation of a quantum phase battery. This quantum element can find key applications in different quantum circuits such as superconducting flux and hybrid qubits [41, 42], multi-valued superconducting quantum memories [17, 43], topological superconducting circuitry [31, 32, 44, 45] and superconducting rectifiers [46].

FIG. 3. Vectorial symmetry of the anomalous phase $\varphi_0$. a, Dependence of the extrinsic anomalous phase $\varphi_{ex}$ on $B_y$. It results in an odd symmetry and non-hysteretic back and forth sweeps (blue and red traces). Inset: The $\varphi_{ex}(B_y)$ dependence obtained from the theoretical model (see SI for details). b, Top: sketch of the interferometer with the reference axes of the in-plane magnetic field ($B_{in}$) and the angle $\theta$ with respect to the nanowire axis. Bottom: the dependence of the anomalous phase $\varphi_{ex}$ on $\theta$ and $B_{in}$. The single traces on the right show the behavior of $\varphi_{ex}$ for a longitudinal $\theta = 0$ (green curve), canted $\theta = \pi/4$ (violet curve) and orthogonal field $\theta = \pi/2$ (blue curve). c, $d\varphi_{ex}/dB_{in}$ vs $\theta$ together with a sinusoidal fit (red curve) from Eq. (4). The slope has been evaluated by a linear fit of the data in b for $|B_{in}| < 10$ mT. The error bar is the RMS of the fit. All the data were recorded at 80 mK of bath temperature.
A further improvement of the phase battery can be envisioned by a controlled doping of the wires with magnetic impurities [47] or by adding a thin layer of a ferromagnetic insulator, like EuS [48], as recently integrated in similar nanowires [49]. From the fundamental point of view, our results will stimulate the discussion on novel concepts of quantum phase batteries and coherent energy storage.

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AUTHOR CONTRIBUTION

E.S., A.I. and O.D. performed the experiment and analyzed the data. R.C., C.S.F., C.G., I.V.T., A.B. and F.S.B. provided theoretical support. M.R. and N.L. fabricated the phase battery on the InAs nanowires grown by V.Z. and L.S. E.S. conceived the experiment together with F.G. that supervised the project. E.S., A.I., I.V.T. and F.S.B. wrote the manuscript with feedback from all authors.
I. DEVICE FABRICATION

Hybrid proximity DC SQUIDs devices were fabricated starting from gold catalyzed n-doped InAs nanowires with typical length of 1.5 μm and a diameter of ~85 nm grown by chemical beam epitaxy [50]. Nanowires were drop-casted onto a substrate consisting of 300 nm thick SiO2 on p-doped Si. Afterwards, a 280 nm-thick layer of positive-tone Poly(methyl methacrylate) (PMMA) electron beam resist were spun onto the substrate. The devices were then manually aligned to the randomly distributed InAs nanowires and patterned by means of standard electron beam lithography (EBL) followed by electron beam evaporation (EBE) of superconducting Ti/Al 5/100 nm electrodes. Low-resistance ohmic contacts between the superconducting leads and the InAs nanowires were promoted by exposing the InAs nanowire contact areas to a highly diluted ammonium polysulfide (NH₄)Sₓ solution, which selectively removes the InAs native oxide and passivates the surface, prior to EBE. The fabrication process was finalized by dissolving the PMMA layer in acetone.

From transport characterization on similar wires and normal metal electrodes [51], we estimate a typical electron concentration n ≃ 2 × 10¹⁸ cm⁻³ and mobility μ ≃ 1200 cm²/Vs. The corresponding Fermi velocity v_F, mean free path l_e and diffusion coefficient D = v_Fl_e/3, are evaluated to be v_F ≃ 2 × 10⁶ m/s, l_e ≃ 30 nm and D ≃ 200 cm²/s.

II. KONDO RESISTANCE R(T)

To quantify the amount of unpaired spins in our system the temperature dependence of the normal-state resistance R(T) has been studied in the range 10 K to 300 K. The data exhibits an upturn at T ≃ 80 K (see Fig. S1) suggesting a Kondo scattering mechanisms between the free electrons and the unpaired spins in the weak-links. Since the InAs nanowires were synthesized without incorporating any magnetic impurity, we conjecture that unpaired spins are originated from oxides states at the nanowire surface. Indeed, the R(T) of a diluted magnetic alloy follows the universal non-monotonic relation [37]

\[ \frac{R(T)}{R_0} = 1 + R_{el-ph}(T) + R_K(T), \] (S1)

where \( R_0 \) is the residual resistance while \( R_{el-ph}(T) \) and \( R_K(T) \) are the contribution given respectively by the electron-phonon and the Kondo scattering. The temperature dependence of the former can be expressed according to the Bloch-Gruneisn model as [52]

\[ R_{el-ph}(T) = a \left( \frac{T}{\theta_D} \right)^5 \int_0^{\theta_D/T} \frac{x^5}{(e^x - 1)(1 - e^{-x})} \mathrm{d}x, \] (S2)

For the Kondo contribution many analytical approximations are available according to the range of temperature investigated. In the full range of temperature the exact solution exist from the numerical renormalization group theory (NRG). In the following we use an empirical fitting function derived as an analytical approximation of the NRG given by [53–56]

\[ \frac{R_K}{R_K} = R_K(0) \left( \frac{T_K^2}{T^2 + T_K^2} \right)^s, \] (S3)

with \( T_K \) related to the actual Kondo temperature \( T_K \) by \( T_K^2 = T_K/(2|s| - 1)^{1/2} \). Note that Eq. S3 is defined such that \( R_K(T_K) = R_K(0)/2 \) and the parameter \( s \) is fixed to \( s = 0.22 \) as expected for a spin 1/2 impurity. In Fig. S1 we show the fit of the experimental data with Eq. S3, from which we extract a Kondo temperature \( T_K = 58 ± 5 K \), a residual magnetic impurity resistance \( R_K(0) = 13.5 ± 0.3 \, \Omega \), a coefficient \( a = 87 ± 6 \, \Omega \) and a Debye temperature \( \theta_D = 551 ± 31 \, K \). From \( R_K(0) \) is possible to estimate the density of unpaired spin, that form the Hamann expression of the residual Kondo resistance in the unitary limit is given by [57]

\[ R_K(0) = \frac{L}{A} \frac{4\pi c h}{nk_F e^2}, \] (S4)

with \( L \sim 80 \, \text{nm} \) junction lengths, \( A \sim \pi r^2 \) with \( r \sim 45 \, \text{nm} \) nanowire cross-sectional area, \( k_F \) Fermi wavevector and \( n \) electron carrier density, from which we estimate the density of magnetic impurities \( c \simeq 1.36 \times 10^{17} \, \text{cm}^{-3} \). This corresponds to a concentration

![Fig. S1. Kondo upturn of the InAs nanowire. Resistance vs temperature \( R(T) \) of one of the devices measured during the cooldown of the refrigerator showing a clear increase of resistance for temperature below 80 K. This behaviour is consistent with the Kondo scattering model as demonstrated by the good fit of the \( R - T \) data with the model in Eq. S3.](image-url)
of ~ 4 ppm (= c/n_{InAs}, with the InAs atomic density n_{InAs} = 3.59 × 10^{22} cm^{-3}) of unpaired spins in the InAs nanowire.

The persistent hysteretic loops of the \( \varphi_0 \)-shift, shown in Fig. 1d-f of the main text, are consistent with the presence of a ferromagnetic background of unpaired spin. To support this hypothesis, we show the first magnetization curve of this spin ensemble measured in the same device in Fig. S3a and b. Initially, the magnetization of the sample is lifted by warming the system above 3 K. Then, the SQUID voltage drop \( \Delta V(\Phi) \) is measured in the absence of the in-plane magnetic field \( B_y \) which is gradually turned on thus polarizing the unpaired spins. The resulting \( \Delta V(\Phi) \) shows no shifts at low \( B_y \) while, only above 5 mT a clear shift is generated. The resulting \( \varphi_{int} \) extracted by fitting \( \Delta V(\Phi) \) is shown in the violet curve of Fig. S3c. By reversing \( B_y \) the \( \varphi_{int} \) then evolves with the typical hysteretic curve of a ferromagnetic system (blue and red curves in Fig. S3c).

**III. SQUID WITH ANOMALOUS JOSEPHSON JUNCTIONS**

The critical current of a SQUID interferometer can be evaluated from the CPR of the two JJs forming the interferometer. Using a sinusoidal CPR, the currents through the two junctions can be written as

\[
i_1 = I_c \sin \left( (\varphi_C - \varphi_L) + \varphi_0^{(1)} \right) \\
i_2 = I_c \sin \left( (\varphi_C - \varphi_R) + \varphi_0^{(2)} \right),
\]

where \( \varphi_L, \varphi_C, \varphi_R \) are the left, central and right superconducting phases and \( I_c \) is the critical current of each JJ.

The supercurrent of the SQUID is the sum of the two contributions \( (I_s = I_1 + I_2) \) and, with the constraint on the superconducting phases of the flux quantization

\[
(\varphi_L - \varphi_C) + (\varphi_C - \varphi_R) + 2\pi \frac{\Phi}{\Phi_0} = 2\pi \mod n,
\]

it has the form

\[
I_s = 2I_c \sin(\delta_0) \cos \left( \frac{1}{2} \left( 2\pi \frac{\Phi}{\Phi_0} + \varphi_{tot} \right) \right),
\]

where \( \delta_0 = \varphi_C - \frac{\varphi_L + \varphi_R}{2} + \frac{\varphi_0^{(2)} + \varphi_0^{(1)}}{2} \) and \( \varphi_{tot} = \varphi_0^{(2)} - \varphi_0^{(1)} \) is the total anomalous phase built in the interferometer. With the geometry depicted in Fig. S2a, the two junctions experience the same in-plane magnetic field orientation but the supercurrents flow in opposite directions resulting in \( \varphi_0^{(1)} = -\varphi_0^{(2)} = \varphi_0 \) and \( \varphi_{tot} = 2\varphi_0 \). The stable state configuration of the SQUID is achieved by minimizing the total Josephson free energy obtained at \( \delta_0 = \pi/2 \), and then the maximum sustainable supercurrent results to be

\[
I_s(\Phi) = 2I_c \left| \cos \left( \pi \frac{\Phi}{\Phi_0} + \varphi_{tot} \right) \right|.
\]

It follows that in absence of magnetic flux, the maximum supercurrent is reduced by a factor \( \sim |\cos(\varphi_{tot}/2)| \) compared to the non-anomalous case as a consequence of the anomalous supercurrent already present in the interferometer. In a more conventional geometry as the one showed in Fig. S2b, the anomalous phases acquired by the two junctions would be the same \( \varphi_0^{(1)} = \varphi_0^{(2)} = \varphi_0 \), making impossible its detection in the phase-to-current readout employed in the present work.

**IV. FIRST “MAGNETIZATION” CURVE**

In this section we repeated the same magnetic characterization of the Josephson phase battery shown in Fig. 2 and 3 of the main text, performed on a different device to demonstrate the high reproducibility of the effect, apart sample-specific details. Notice that the behaviour of \( \varphi_{tot} \) and \( \varphi_{int} \) (Fig. S4) is qualitatively similar, but with a smaller total phase shift of ~ 0.4\( \pi \) stemming for a weaker exchange interaction induced by the unpaired-spin. Moreover the angle dependence of \( \varphi_{ext}(\theta) \) shown in Fig. S5 is in very good agreement with the evolution observed in Fig. 2 and expected from the model presented in the next section.

**V. SUPPLEMENTARY DEVICE MEASURED**

The origin of the anomalous phase \( \varphi_0 \) is the singlet-triplet conversion mediated by the SOC, which in the...
normal state corresponds to the charge-spin conversion [2]. The calculations of the anomalous Josephson current in $\varphi_0$-junctions have been done for ideal planar S-N-S junctions, in which the superconducting electrodes and the normal region with SOC are separated by sharp boundaries [1, 2, 58], where the singlet-triplet coupling takes place only at N region. As shown in Ref. [2], this assumption leads to a monotonically increase of the anomalous phase $\varphi_0$ as a function of the applied magnetic field, which contrasts with curves extracted from our experiment (see Fig. 3a in the main text). It is however clear that our experimental setup (Fig. 1 in the main text) differs from an ideal S-N-S junction. Indeed, in each junction, the superconducting leads are covering part of the wires over distances larger than the coherence length. This means that the SOC, and hence the spin-charge conversion, is also finite in the portion of the wire covered by the superconductor. As we show in this section, this feature is important to understand the experimental findings; in particular, the dependence to $\varphi_0$ from the external magnetic field. In this calculation, we focus on the dependence of $\varphi_0$ on the $y$ direction of the field, i.e., $B_{\text{in}}$ at $\theta = \pi/2$ (see Figs. 3a and b in the main text).

To be specific, we consider the junction sketched in Fig. S6. We assume an infinite diffusive quasi-one dimensional nanowire along the $x$ axis, which is partially covered by two semi-infinite Al superconducting leads at $x < L/2$ and $x > L/2$. We assume, for simplicity, that the proximity effect is weak and that the wire is diffusive. In such a case, the condensate function, which determines the Josephson current, obeys the linearized Usadel equation, which results in two coupled differential equations for the singlet and triplet components as shown in Ref. [2]. Because the wire lies on a substrate plane, the system has an uniaxial asymmetry in the $z$ direction perpendicular to the substrate (see Fig. S6). In the presence of SOC, this allows for a gradient singlet-triplet coupling generated by a differential operator of the form $C_{k}^{s,t} \partial_{k} \sim (\hat{z} \times \nabla)^{a}$, which converts a scalar (the singlet) into a pseudovector (the triplet) and vice versa [2, 58]. We consider the case when the external field is applied in the $y$ direction, and hence, the superconducting condensate function has the form $f = f_{s} + i f_{t} \text{sgn} \sigma^{y}$, where $f_{s,t}$ are the singlet and triplet components and $\omega$ the Matsubara frequency. The linearized Usadel equation reads:

$$
\frac{D}{2} \nabla^{2} f_{s} - |\omega| f_{s} + (h - i D \kappa_{sc} \partial_{s}) f_{t} = 0,
$$

$$
\frac{D}{2} \nabla^{2} f_{t} - |\omega| f_{t} - (h - 2i D \kappa_{sc} \partial_{s}) f_{s} = 0.
$$

Here $D$ is the diffusion coefficient and $h = \mu_{B} g_{s} B_{\text{in}}/2$ is the Zeeman field. The last term in both equations describes the spin-charge conversion due to the SOC. It is proportional to the effective inverse length $\kappa_{sc}$ and the spatial variation of the condensate in the direction of the wire axis. The form of this term is determined by the uniaxial anisotropy of the set up in combination with the fact that we assume that the field is applied only in $y$ direction.

Equation (S9) is written for the full 3D geometry. To obtain an effective 1D Usadel equation, we integrate Eq. (S9) over the wire cross-section and use boundary conditions imposed on the condensate function at the surface of the wire. In the part of the wire which is covered by the superconductor, the interface between the wire and the superconductor is described by the linearized Kupryanov-Lukichev boundary condition

$$
\partial_{s} f_{s}|_{\text{InAs/Al}} = \gamma f_{\text{BCS}} e^{i\phi},
$$

where $\gamma$ is a parameter describing the InAs/Al interface, $f_{\text{BCS}} = \Delta / \sqrt{\Delta^{2} + \Delta_{s}^{2}}$ is the BCS bulk anomalous Green’s function in the superconducting leads, and $\phi$ is the phase of the corresponding lead. In the uncovered parts of the wire, we impose a zero current flow which corresponds to $\partial_{x} f_{s,t}|_{\text{InAs/vac.}} = 0$. The integration of Eq. (S9) over the
FIG. S4. **Charging loops of the Josephson phase battery (second device).** a, Voltage drop $\Delta V(\Phi)$ at constant current bias $I = 1 \mu A$ vs in-plane magnetic field $B_y$ applied orthogonal to the nanowire axis. At large $|B_y|$, the amplitude of $\Delta V(\Phi)$ is lowered due to the suppression of superconductivity inside the wire. Each trace is vertically offset for clarity. b, Selected traces $\Delta V(\Phi)$ extracted from a for different $B_y$. Data are vertically offset for clarity. c, Extracted phase shift $\phi_{tot}$ from the curves in a. d, Color plot of the persistent voltage drop $\Delta V(\Phi)$ measured at $B_y = 0$ after the magnetic field was swept to the values shown on the y-axis. e, Selected traces $\Delta V(\Phi)$ corresponding to the cuts in d. f, Intrinsic phase shift $\phi_{int}$ extracted from d. $\phi_{int}$ stems from the ferromagnetic polarization magnetic impurities. All data were recorded at 80 mK of bath temperature.

cross-section of the wire results in two coupled equations for the singlet and triplet components

$$\begin{align*}
\partial_x^2 f_s - \kappa_s^2 f_s + \left(\kappa_s^2 - 2i\kappa_{sc}\partial_x\right) f_t &= S(x), \\
\partial_x^2 f_t - \kappa_s^2 f_t - \left(\kappa_h^2 - 2i\kappa_{sc}\partial_x\right) f_s &= 0,
\end{align*}$$

with

$$S(x) = \gamma f_{BCS} \left[ \Theta \left( x - \frac{L}{2} \right) e^{ix} + \Theta \left( -x - \frac{L}{2} \right) e^{-ix} \right],$$

$$\kappa_s^2 = \frac{2|\tau|}{\tau}, \quad \kappa_h^2 = \frac{2h}{\tau D},$$

and $\varphi$ is the phase difference between these two Al leads. After a cumbersome but straightforward procedure, we solve Eq. (S11) for continue and finite $f_s, f_t$. From the knowledge of the singlet and triplet components one determines the Josephson current as follows [2]:

$$j(x) = \frac{\pi \sigma DT}{e} \sum_\omega \text{Im}\{ f_s^* \partial_x f_s - f_t^* \partial_x f_t - i\kappa_{sc} (f_s^* f_t + f_s f_t^*) \}. $$

The resulting current can be written as $j = I_c \sin(\varphi + \varphi_0)$, with the anomalous-phase given by

$$\varphi_0 = \arctan \left\{ \frac{\sum_\omega \text{Im}\left\{ f_{BCS} e^{-qL} \frac{\sinh(\kappa_{sc}L)}{q^2 + \kappa_{sc}^2} + 2q\kappa_{sc} \cosh(\kappa_{sc}L)} \right\}} {\sum_\omega \text{Re}\left\{ f_{BCS} e^{-qL} \frac{\cosh(\kappa_{sc}L)}{q^2 + \kappa_{sc}^2} + 2q^* \kappa_{sc} \sinh(\kappa_{sc}L)} \right\}} \right\},$$

where $q^2 = \kappa^2 + \kappa_{sc}^2 - i\kappa_{sc}^2$. In order to compare with the experimental data, we assume a Rashba-like SOC
FIG. S5. **Vectorial symmetry of the anomalous phase $\varphi_0$ (second device).** a, Dependence of the extrinsic anomalous phase $\varphi_{ex}$ on $B_y$. b, Evolution of the anomalous phase $\varphi_{ex}$ on $\theta$ and $B_{in}$. c, $d\varphi_{ex}/dB_{in}$ vs $\theta$ together with a sinusoidal fit (red curve) from Eq. (4). The slope has been evaluated by a linear fit of the data in b for $|B_{in}| < 10$ mT. The error bar is the RMS of the fit. All the data were recorded at 80 mK of bath temperature.

FIG. S6. **Schematic view of the S-N-S junctions.** At $|x| > L/2$, the InAs nanowire (red region) is partially covered by the Al superconducting leads (dark blue regions). The gray region corresponds to the substrate. This schematic view corresponds to the z-x plane of Fig. 3b (top panel) in the main text.

and use the expression derived in Ref. [2] for the spin-charge coupling parameter, namely $\kappa_{sc} = 2\tau_0 \alpha^3 m^* s^2 / \hbar^5$. By using typical values for the parameters of a InAs/Al system: $\xi_0 \approx 100$ nm, $\Delta \approx 150$ µeV, $m^* = 0.023m_e$, $T \approx 25$ mK, $g_s \approx 12$, and $\alpha \approx 0.24$ eVÅ, we find the $\varphi_0(B_{in})$ dependence corresponding to the one shown in Fig. 3a of the main text. We see that our model provides a good qualitative explanation of the two main observed features. Namely, the linear increase of $\varphi_0$ for small fields and a kind of saturation at $\varphi_0 \approx \pm 0.5\pi$.

In Fig. S7, we show different $\varphi_0(B_{in})$ curves obtained from our general expression (S14). Whereas for small fields the experimental slope (dashed black line) can be obtained from different values of the parameters, the behaviour of $\varphi_0$ at larger fields depends strongly on these parameters.

Indeed, it is important to emphasize that the saturation value at $\varphi_0 \approx \pm 0.5\pi$ is not an universal property of the phase-battery. This value depends on the intrinsic properties of the system. In particular, larger values of the SOI $\alpha$ leads to larger values of $\varphi_{ex}$ at values of the field larger than those accessed in the experiment.

This is shown in Fig. (S7)b, where we plot the $\varphi_0(B_{in})$ dependence for different values of $\alpha$, with $T \approx 10$ mK. As in Fig. (S7)a, we change the $g_s$ value to maintain the experimental slope in the low-field region.

The linear behavior for the low-field region is shared by all the $\varphi_0(B_{in})$ curves, as shown in Fig. (S7). In this regime, we can thus find the slope value by linearizing Eq. (S14):

$$\varphi_0 \approx C_1 B_{in} + O(B_{in}^3),$$

with $C_1 \approx 0.035\pi$ mT$^{-1}$, which is in agreement with the value extracted from the experiment.
FIG. S7. **Theoretical model of the extrinsic anomalous phase.** The dependence of the extrinsic anomalous-phase on the magnetic field applied in $y$ direction ($B_{in}$ at $\theta = \pi/2$) for a) different temperatures, with $\alpha \simeq 0.24 \text{ eVÅ}$ and for b) different values of $\alpha$, with $T \simeq 10 \text{ mK}$. In a), the solid blue line coincides with the one shown in Fig. 3a of the main text, with $T \simeq 25 \text{ mK}$ and $g_s \simeq 12$. For the dashed orange line, we choose $T \simeq 10 \text{ mK}$ and $g_s \simeq 5$, and for the dashed-dotted line, $T \simeq 5 \text{ mK}$ and $g_s \simeq 2$. In b), the solid blue line corresponds to $\alpha \simeq 0.1 \text{ eVÅ}$ and $g_s \simeq 37$, the dashed orange line to $\alpha \simeq 0.18 \text{ eVÅ}$ and $g_s \simeq 7$, and the dashed-dotted green line to $\alpha \simeq 0.4 \text{ eVÅ}$ and $g_s \simeq 3$. In both a) and b), the dashed black line corresponds to the measured slope at low fields.


